

TA-F7/TA-F7B

**UK Model
AEP Model**

TA-F7: silver panel
TA-F7B: black panel



INTEGRATED STEREO AMPLIFIER

SPECIFICATIONS

GENERAL

Power Requirements: 220V, 50/60 Hz (AEP model)
240V, 50/60 Hz (UK model)

Power Consumption: 400W (AEP model)
410W (UK model)

Dimensions: Approx. 430 (w) x 170 (h) x 420 (d) mm
17 (w) x 6 3/4 (h) x 16 5/8 (d) inches
Including projecting parts and controls

Weight: Approx. 20.3 kg, 44 lb 12 oz (net)
Approx. 24.3 kg, 53 lb 9 oz (with shipping
carton)

PREAMPLIFIER SECTION

Harmonic Distortion: Less than 0.015% at rated output
(AEP model)
Less than 0.015% at 1W (UK model)

IM Distortion: (60 Hz: 7 kHz = 4:1)
Less than 0.015% at rated output
(AEP model)
Less than 0.015% at 1W (UK model)

Frequency Response: PHONO 1, 2 RIAA equalization curve ± 0.2 dB
TUNER
AUX 1, 2 } 5–100,000 Hz ± 0 dB
TAPE 1, 2 }

Tone Controls: BASS ± 10 dB at 30 Hz (TURNOVER
FREQ 150 Hz)
 ± 10 dB at 60 Hz (TURNOVER
FREQ 300 Hz)
TREBLE ± 10 dB at 20 kHz (TURNOVER
FREQ 4 kHz)
 ± 10 dB at 40 kHz (TURNOVER
FREQ 8 kHz)

Filters: LOW 12 dB/oct. below 30 Hz
HIGH 12 dB/oct. above 9 kHz

— Continued on next page —

SAFETY-RELATED COMPONENT WARNING !!

COMPONENTS IDENTIFIED BY SHADING AND MARK ON THE SCHEMATIC DIAGRAMS, EXPLODED VIEWS AND IN THE PARTS LIST ARE CRITICAL TO SAFE OPERATION. REPLACE THESE COMPONENTS WITH SONY PARTS WHOSE PART NUMBERS APPEAR AS SHOWN IN THIS MANUAL OR IN SUPPLEMENTS PUBLISHED BY SONY.

SONY®
SERVICE MANUAL

Inputs:

	Sensitivity	Impedance	Maximum Input Capability (THD 0.015% at 1 kHz)	S/N (weighting network, input level)
PHONO 1 PHONO 2	2.5 mV (-50 dB)	50 kΩ	250 mV (-10 dB)	75 dB (A, 2.5 mV)
TUNER AUX 1, 2 TAPE 1, 2	150 mV (-14.5 dB)	50 kΩ	—	95 dB (A, 150 mV)

Outputs:

	Output Level	Impedance
REC OUT 1,2	150 mV	10 kΩ
PRE OUTPUT	1 V	1.5 kΩ

POWER AMPLIFIER SECTION
Continuous RMS Power Output:

(rated output) Both channels driven simultaneously
 At 20–20,000 Hz
 (Less than 0.015% 70 + 70W (8Ω)
 harmonic distortion) According to DIN 45500
 70 + 70W (8Ω)

Power Bandwidth: 5–40,000 Hz, IHF (8Ω, 0.015 THD)

Damping Factor: 60 (8Ω, 1 kHz)

Harmonic Distortion: Less than 0.015% at rated output
 Less than 0.015% at 1W output

IM Distortion: (60 Hz:7 kHz = 4:1)
 Less than 0.015% at rated output
 Less than 0.015% at 1W output

Frequency Response: dc-100,000 Hz ±⁰₁ dB (1W)

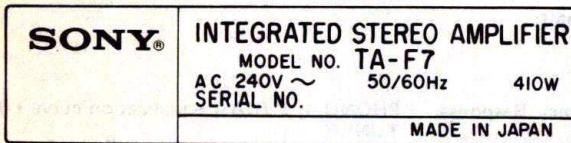
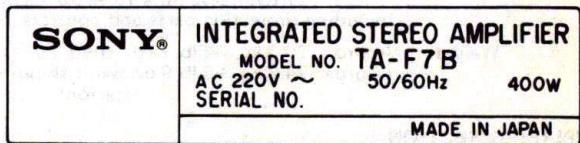
S/N Ratio: Greather than 110 dB, short-circuited input

Residual Noise: Less than 0.12 mV

Inputs: POWER INPUT
 Sensitivity 1V (for rated output)
 Impedance 100 kΩ

Outputs: SPEAKER A, B
 Accept speakers of 8Ω or more
 HEADPHONES
 Accepts low- and high-impedance stereo headphones

0 dB = 0.775V

MODEL IDENTIFICATION
— Specification Label —
UK model

AEP model


SECTION 1 OUTLINE

1-1. CIRCUIT DESCRIPTION

1-1-1. Equalizing Amplifier

Refer to Fig. 1-1. The input signal from PHONO 1 or PHONO 2 goes to the gate G1 of the dual-FET differential amplifier Q101 and the feedback signal from the output goes to the gate G2. Q101 amplifies these two input signals, and its output signals at the drains D1 and D2 are in reversed phase. Q106 and D101 are the load of the differential amplifier and compose a current-mirror circuit. This current mirror makes the differential amplifier have more gain and less distortion by re-using the output current in other than the load of the differential amplifier and making it a load current. The output signal appeared in the drain D1 next goes to the base of Q107.

Q107 and Q108 compose a darlington circuit, and this circuit has a proper gain by having a constant-current source Q109. Q102 in the source return of the differential amplifier Q101 is a constant-current source and serves as an infinite impedance against the input signal to the differential amplifier. Transistor Q102 is used instead of a large resistor in this stage, because the dual FET Q101 is drawing a relatively large current from the limited B+ voltage to improve audio quality.

Q103 and Q104 compose a voltage regulator and the voltage V_0 , namely the base-bias of Q102, is maintained constant to make Q102 stable. The current I_1 which flows through the constant-current source Q102 is expressed as

$$I_1 = \frac{V_0 - V_{BE1}}{R106}$$

where $V_0 = V_{BE2} + V_1$

V_1 is determined by I_0 which flows through R112 by V_{BE2}

So, I_1 is determined by V_{BE1} and V_{BE2} and is independent upon B+ and B- voltages, namely I_1 is constant.

Furthermore, this equalizing amplifier is stabilized dc-current-wise by utilizing a dc feedback circuit of Q105 as well as the dependent feedback circuit to produce the RIAA deemphasis curve. Here, Q105 serves as a voltage follower and its dc gain G is determined as

$$G = \frac{R110}{R107} \approx 30 \text{ dB}$$

The lower-side cutoff frequency is determined by R116 and C107 in the gate circuit of Q105.

The RIAA curve to be used as a record amplifier is produced by the feedback components C105, C106, R108, R109, R120 and C109. And the output

signal is fed back to the gate G2 of Q101, thus making a voltage feedback loop.

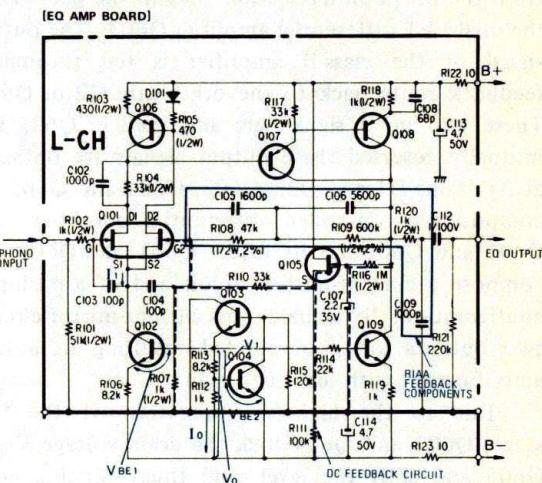


Fig. 1-1.

1-1-2. Power Amplifier

(1) Class-A Amplifier

Refer to Fig. 1-2 and Fig. 1-3. The output signal from the preamplifier section goes to the gate G1 of the dual-FET differential amplifier Q605. The output signal of the class-B amplifier is fed through a feedback route back to the other gate G2 of Q605. These two input signals are amplified in Q605 and mutually reversed-phase output signals are obtained at its drains D1 and D2. Q603, Q604 and Q605 are composing a cascoded differential amplifier, and Q601 and Q602 are its load. Q601 and Q602 also compose a current-mirror circuit and of a push-pull configuration. By utilizing this current-mirror circuit, two outputs are compounded resulting in a high amplification with less distortion.

Due to the high-gain operation of the first stage, Q603 and Q604 lock the drain voltage V_D of Q605 and shift the level, and thus reducing noise component produced by the drain current. The locked drain voltage V_D is expressed as

$$V_D \doteq V_{CC} \times \frac{R_{604}}{R_{603} + R_{604}} \doteq 15\text{ V}$$

The output signal at the drain of Q603 next goes to the class-A cascoded amplifier composed of Q607 and Q608 which has a constant-current load Q611. And its output signal is next applied to and voltage amplified by the following class-B amplifier.

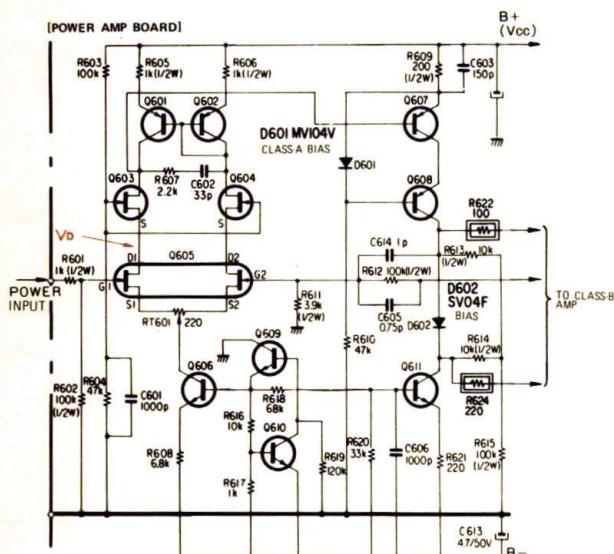


Fig. 1-2.

These two cascaded amplifiers composed of Q603 to Q605, and of Q607 and Q608 are the combination of the common emitter (or source) and

common base (or gate) circuits. In these amplifiers, the mirror effect due to the feedback capacitor from the output side does not present, so they are increasing the transmission capability of high-frequency component. Furthermore, R607 and C602 are connected inbetween the drains of Q603 and Q604 of the first-stage cascaded differential amplifier to make the load impedance low at high frequency, and thus reducing the fluctuation of the amplifier gain.

(B) Class-B Amplifier

Refer to Fig. 1-3. These class-B amplifiers are cascode-type amplifiers utilizing features of the bipolar transistors and V-FETs, and they are improving the signal-transmission characteristics.

Q616 is a class-B driver and emitter follower followed by the final-stage power amplifier. The final-stage power amplifier is a pure-complementary circuit composed of cascode configuration of Q618, Q619 and Q901 to Q903.

When the bipolar transistors and V-FETs are connected in a cascode configuration, V_{CE} of the bipolar transistors Q618 and Q619 becomes the reversed bias of the gate of V-FET and this bias prevents V-FET from damaging, otherwise V-FET may be damaged by a huge current equivalent to I_{DSS} . This reversed bias of V-FET provides a good rejection characteristic against the fluctuation of the power supply voltage. In this configuration, the voltage applied to the bipolar transistor becomes as low as around 15 V and bipolar transistors with a high transition frequency f_T can be combined.

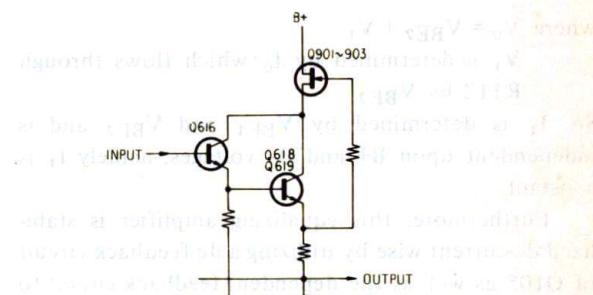


Fig. 1-3.

1-1-3. Power Supply

Refer to Fig. 1-4. This regulated power supply provides a power for the class-B amplifier. This voltage regulator uses a constant-current circuit Q706 in the base-bias circuit of the control transistors Q704 and Q705. And this voltage regulator provides a high input impedance, low output impedance and a good regulation against the fluctuation in the input voltage.

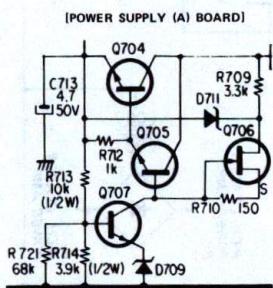


Fig. 1-4.

Fig. 1-5 shows the basic voltage-regulating circuit.

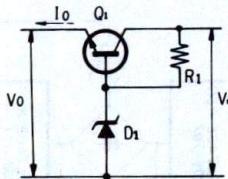


Fig. 1-5.

The voltage regulation factor is expressed as

$$\frac{\Delta V_o}{\Delta V_i} \approx \frac{Rd}{R1 + Rd}$$

where, ΔV_o = fluctuation of output voltage

ΔV_i = fluctuation of input voltage

Rd_1 = active resistance of D1

Accordingly, on a constant Rd_1 , the larger $R1$ the better a voltage regulation. In the circuit in Fig. 1-4, a good voltage regulation is obtained by utilizing an FET-type constant-current source and a large $R1$.

The output impedance of the circuit in Fig. 1-5 is expressed as

$$R_o \approx \frac{\Delta V_o}{\Delta I_o}$$

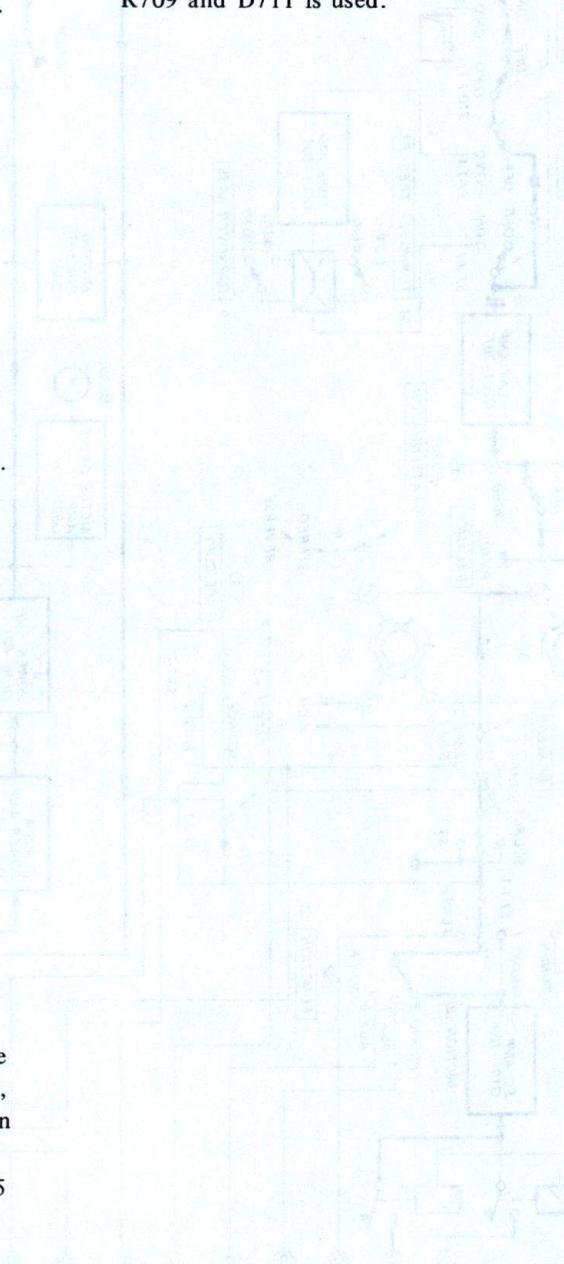
$$\approx \frac{Rb + Rd}{1 + h_{FE}}$$

where, Rb = base resistance of Q1

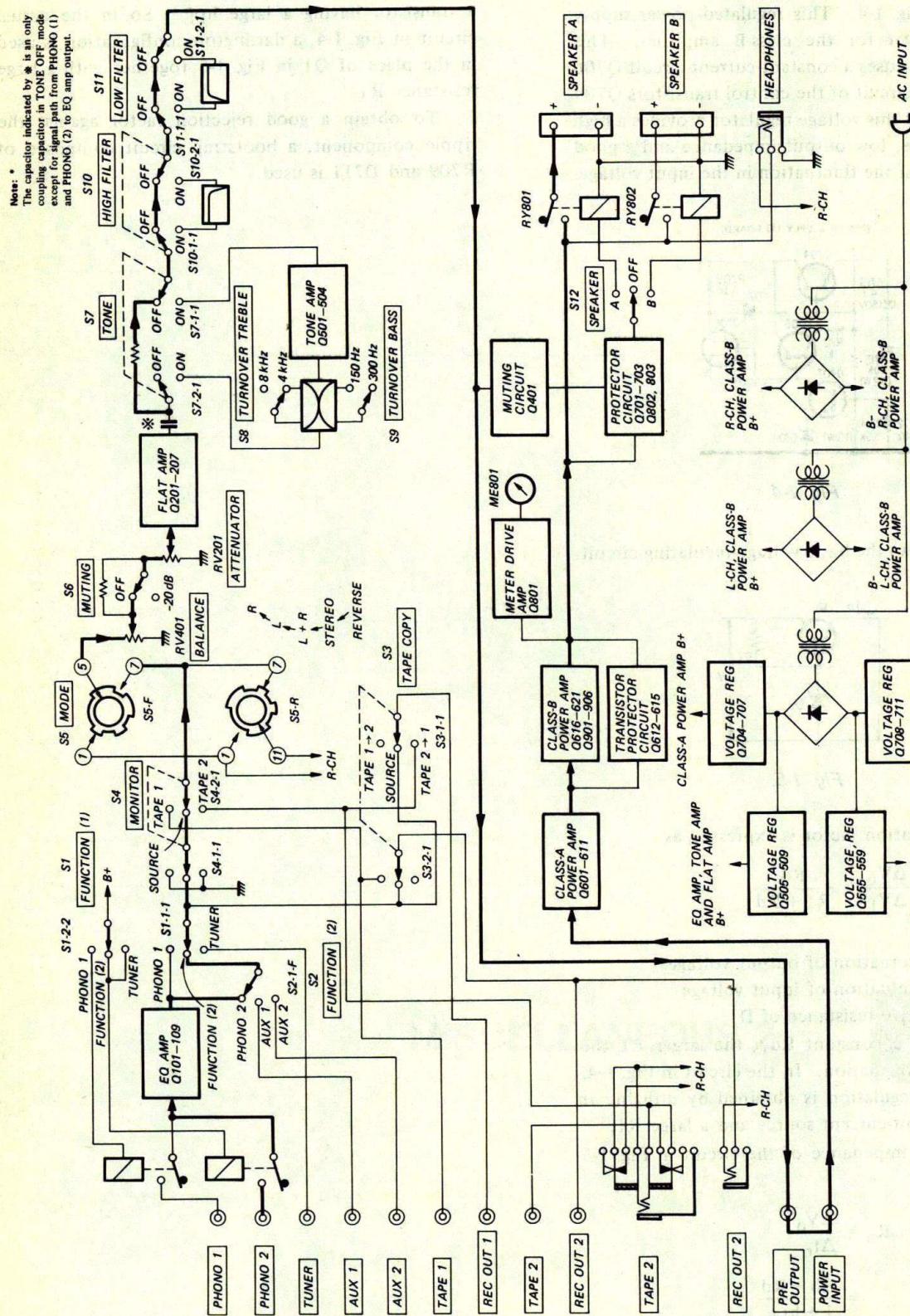
h_{FE} = current amplification factor of Q1

Therefore, a low output impedance is obtainable with a transistor having a large h_{FE} . So in the actual circuit in Fig. 1-4, a darlington configuration is used in the place of Q1 in Fig. 1-5 together with a large resistance $R1$.

To obtain a good rejection factor against the ripple component, a bootstrap circuit composed of R709 and D711 is used.

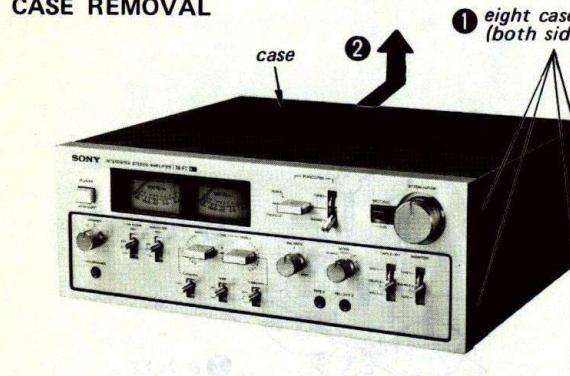


1-2. BLOCK DIAGRAM

SECTION 2
DISASSEMBLY

Note: Remove in the numerical order.

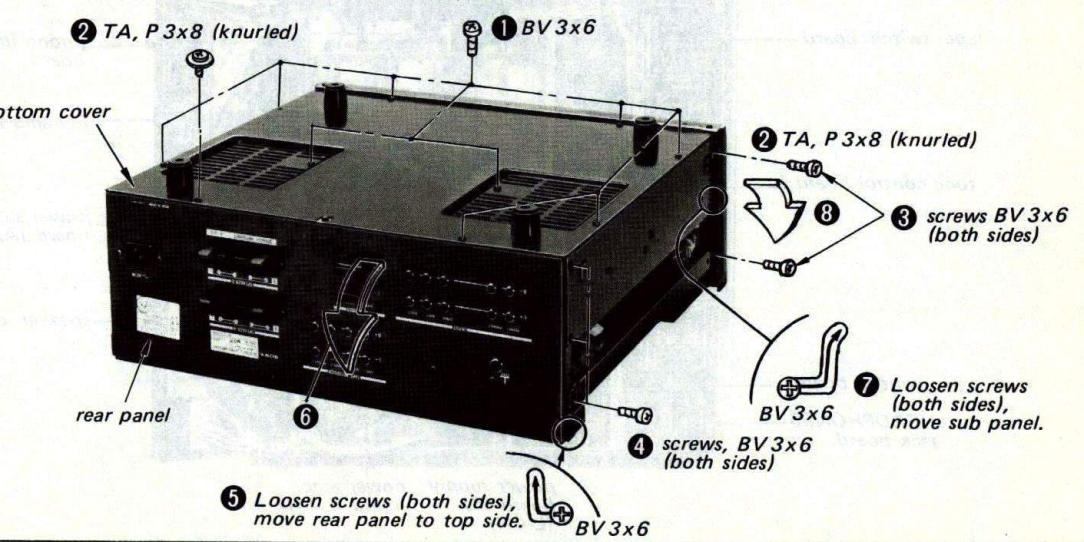
CASE REMOVAL



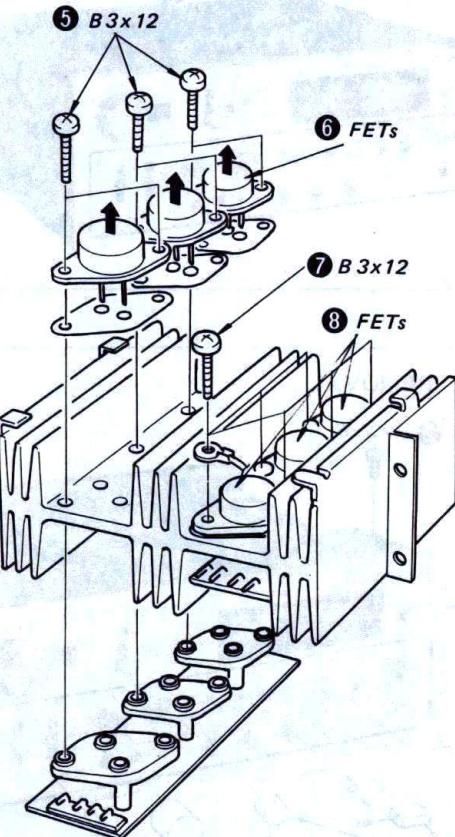
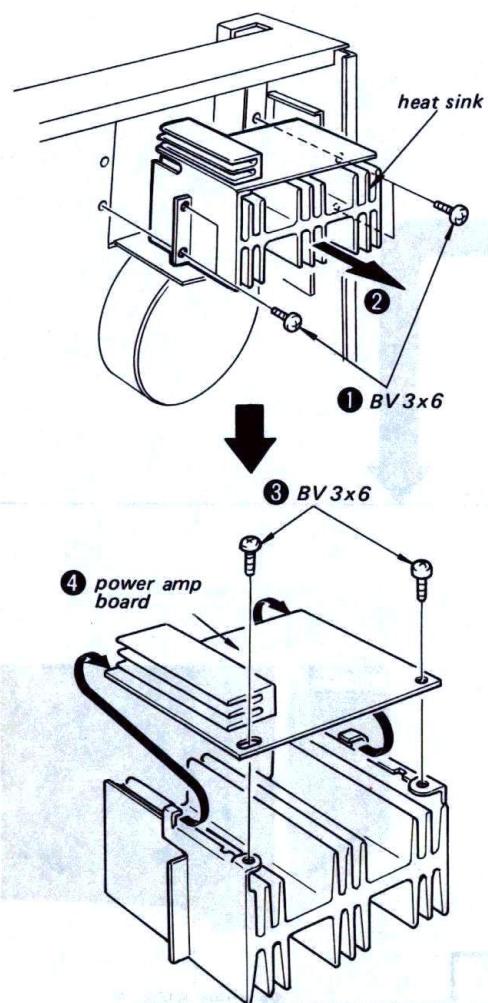
PANEL REMOVAL



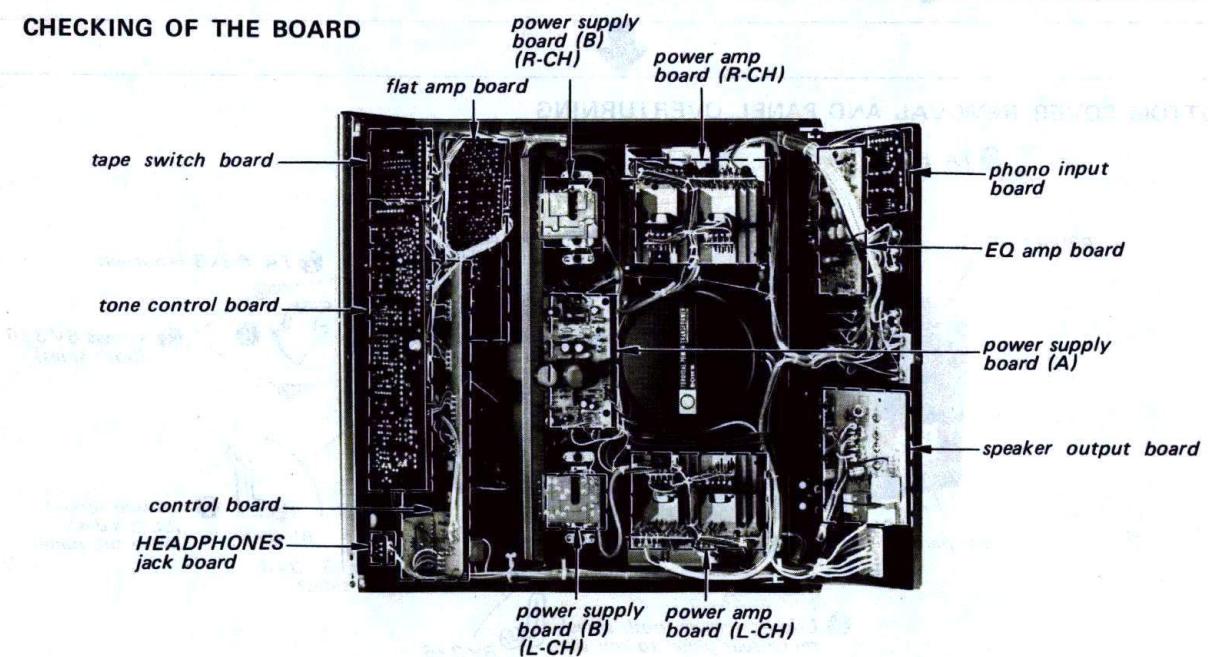
BOTTOM COVER REMOVAL AND PANEL OVERTURNING



POWER V-FET REPLACEMENT

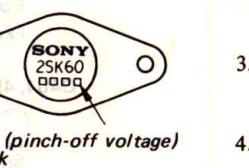


CHECKING OF THE BOARD



SECTION 3
ADJUSTMENT

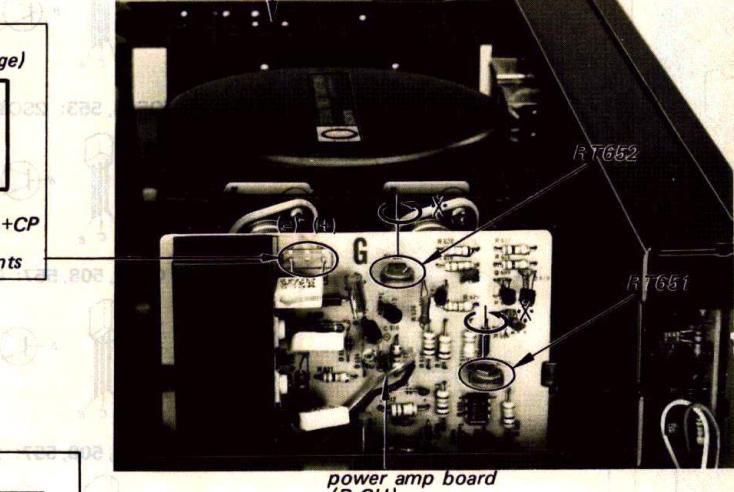
Note: 1. As outlined in the circuit description, this set uses bipolar transistors and V-FETs in cascode circuit to maintain stable biasing. When replacing the three P-channel V-FETs 2SK60 and/or the three N-channel V-FETs 2SJ18 in each channel, use three matched ones which have the same V_p (pinch-off voltage)-rank figure printed on them as shown below. The fluctuation of the V_p rank of the three can be acceptable on one-rank-difference basis.



DC Balance Adjustment

1. Connect a dc millivoltmeter to SPEAKER terminals.
2. Turn POWER switch ON. Adjust RT601 (L-CH) and RT651 (R-CH) for 0V reading on the millivoltmeter.

VOM (dc V range)



Note:

When the controls are turned in the arrowed direction \times , voltage reading increases.

Same power-amp circuit boards are used in both L- and R-channels. Component reference numbers printed on the circuit board are different from the circuit and mounting diagrams.

Power Meter Adjustment

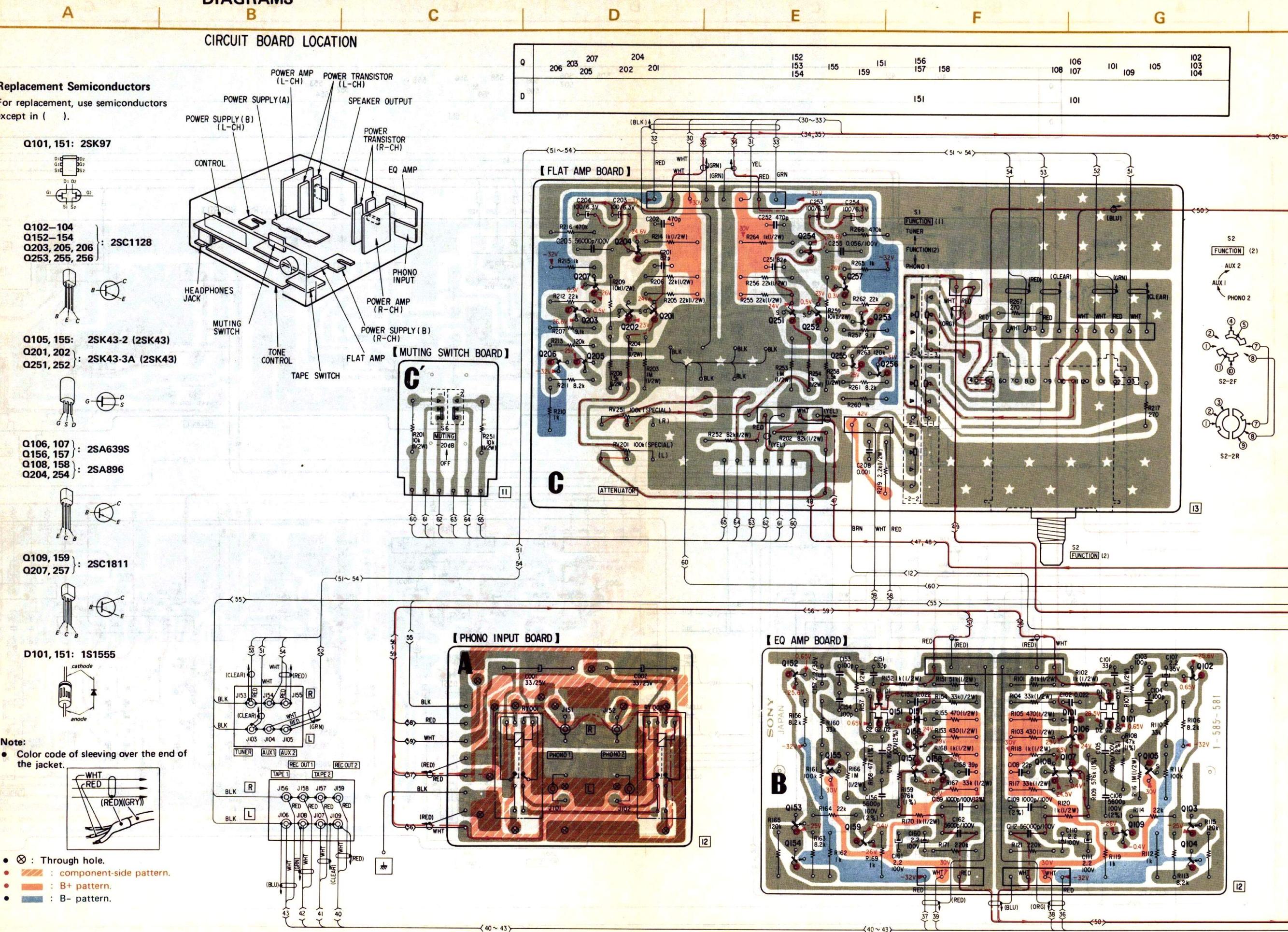
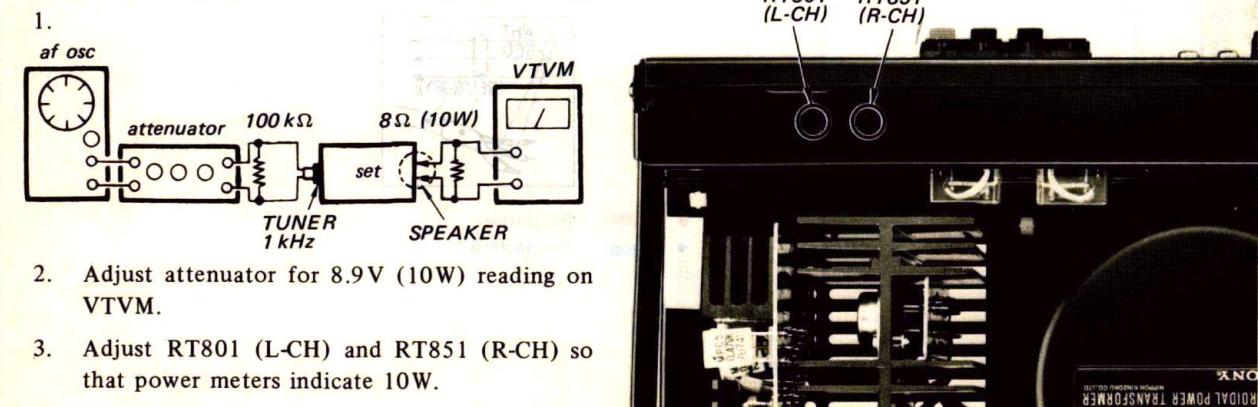
Setting: ATTENUATOR control: maximum
HIGH FILTER switch: OFF
LOW FILTER switch: OFF
MONITOR switch: SOURCE
FUNCTION switch: TUNER

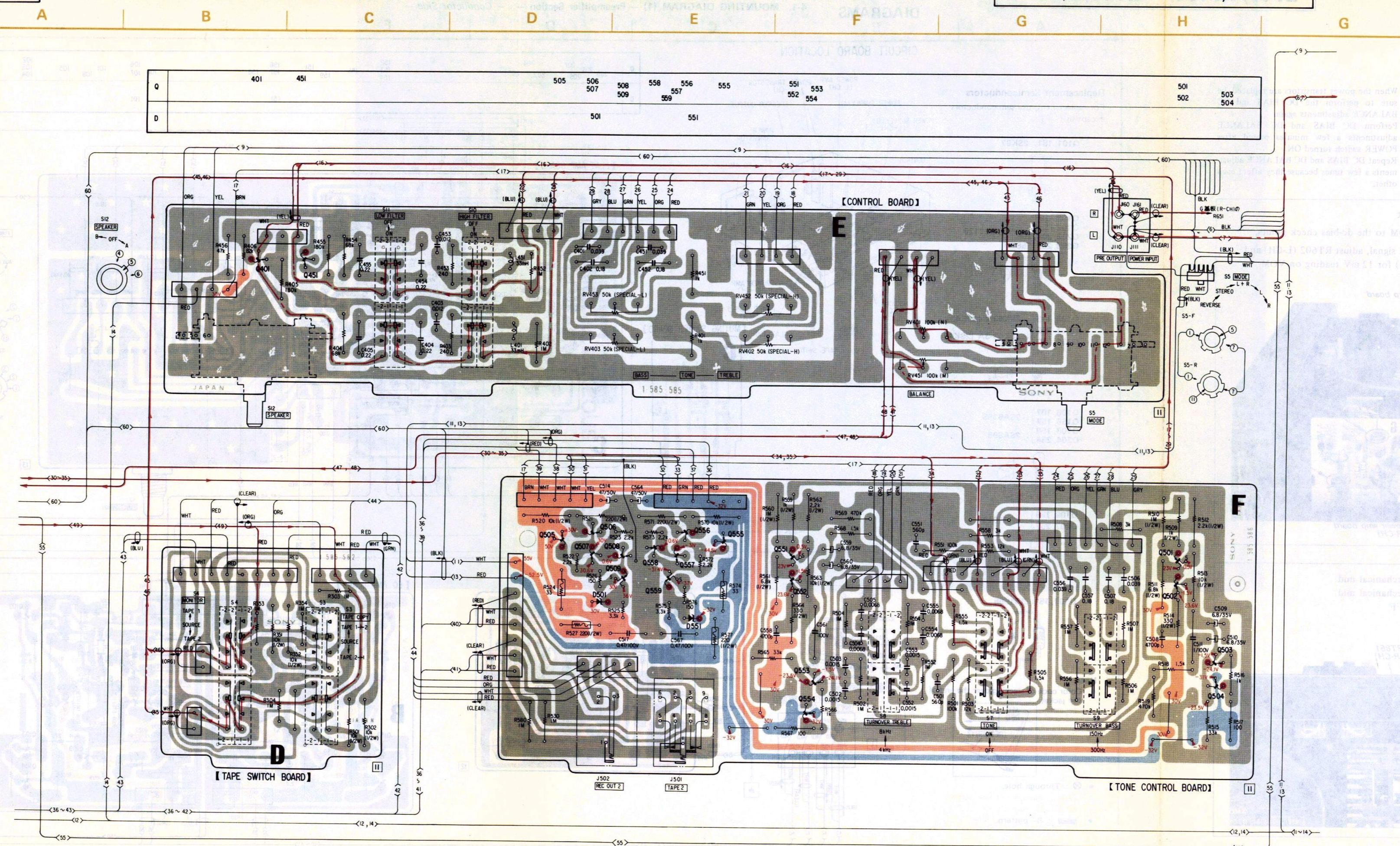
TONE controls:
BALANCE control:
MUTING switch:

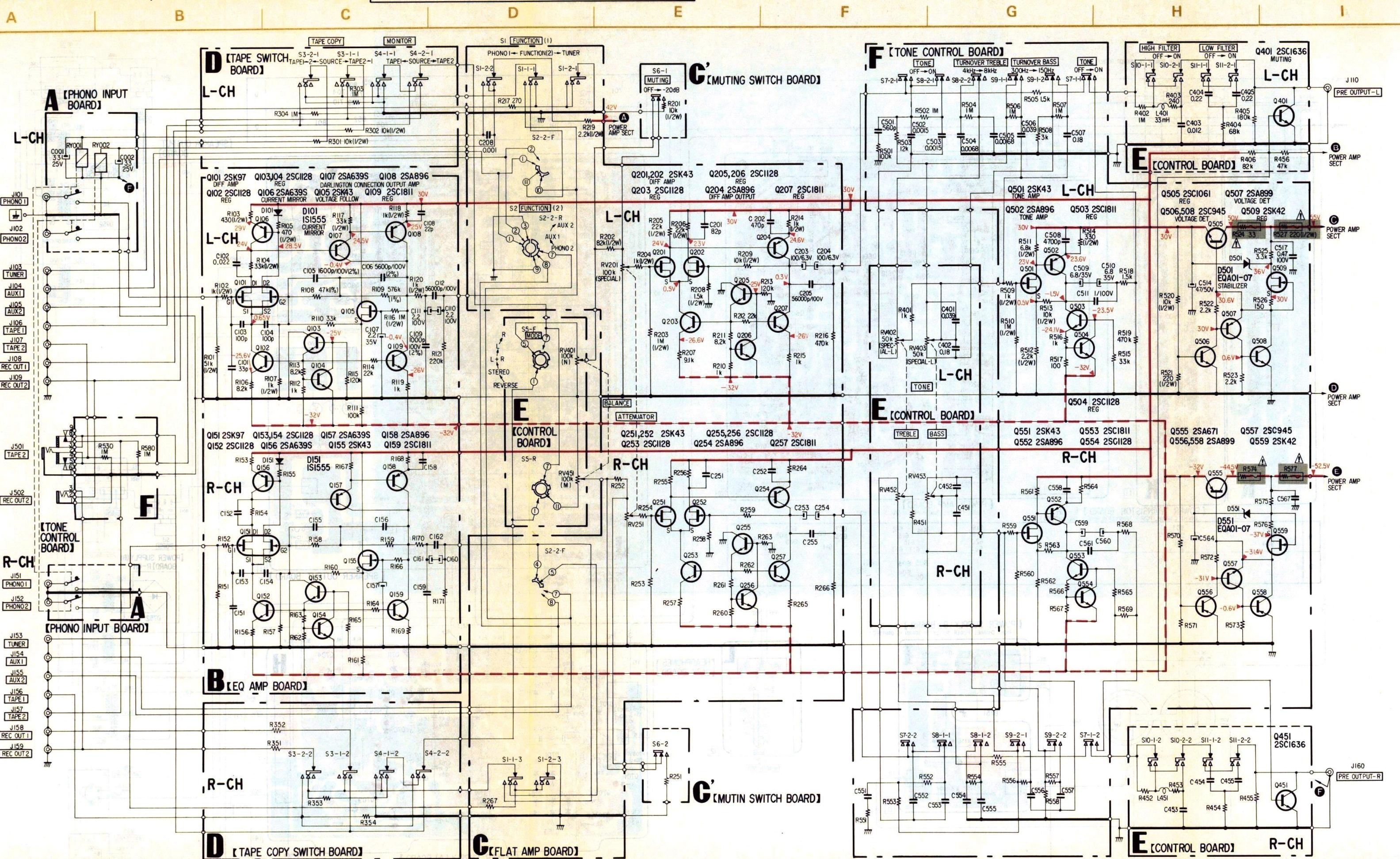
mechanical mid
mechanical mid

Procedure:

1. af osc attenuator 100 k Ω 8 Ω (10W) VTVM TUNER 1 kHz SPEAKER
2. Adjust attenuator for 8.9V (10W) reading on VTVM.
3. Adjust RT801 (L-CH) and RT851 (R-CH) so that power meters indicate 10W.







Note: The components identified by shading and  mark are critical for safety. Replace only with part number specified.

Note:

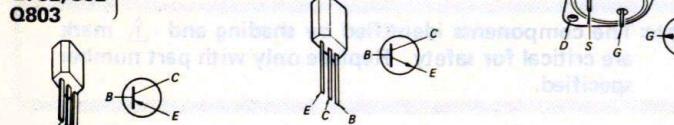
- Components for right channel have same values as for left channel. Reference numbers are coded from.
- All capacitors are in μF unless otherwise noted. $\text{pF} = \mu\text{F}$
50WV or less are not indicated except for electrolytics.
- All resistors are in ohms, $\frac{1}{4}\text{W}$ unless otherwise noted.
 $\text{k}\Omega = 1000\Omega$, $\text{M}\Omega = 1000\text{k}\Omega$
-  : fusible resistor.
- 0% indicates component tolerance.
-  : B+ bus.
-  : B- bus.
-  : panel designation.
- Readings are taken under no signal conditions with a VOM (20 $\text{k}\Omega/\text{V}$).

f. No.	Switch	Position
S1	FUNCTION (1)	FUNCTION (2)
S2	FUNCTION (2)	PHONO 2
S3	TAPE COPY	SOURCE
S4	MONITOR	SOURCE
S5	MODE	REVERSE
S6	MUTING	OFF
S7	TONE	OFF
S8	TURNOVER TREBLE	4 kHz
S9	TURNOVER BASS	300 Hz
S10	HIGH FILTER	OFF
S11	LOW FILTER	OFF

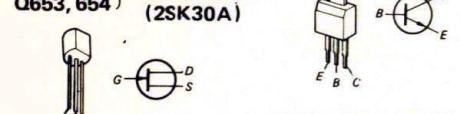
Replacement Semiconductors

For replacement, use semiconductors except in ().

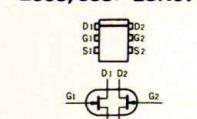
Q601, 602 } Q613, 614 } Q904-906 } : 2SJ18
 Q651, 652 } Q663, 664 } Q954-956 } : 2SC634A
 Q612, 615 } : 2SA678 Q701, 703 }
 Q662, 665 } Q801, 851 }
 Q702, 802 }
 Q803 }



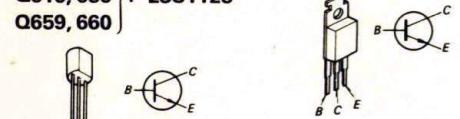
Q616, 666: 2SC1124
Q603, 604 } : 2SK30A-GR



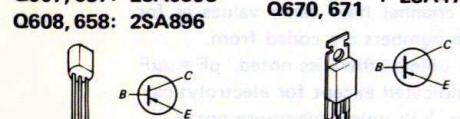
Q605.655: 2SK97



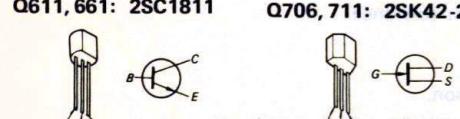
Q606, 609 }
Q610, 656 } : 2SC1128



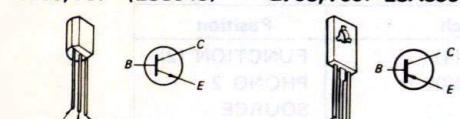
Q710:
Q620, 621



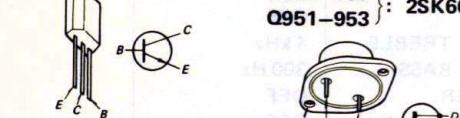
E C B



Q705, 707: (2SC94)

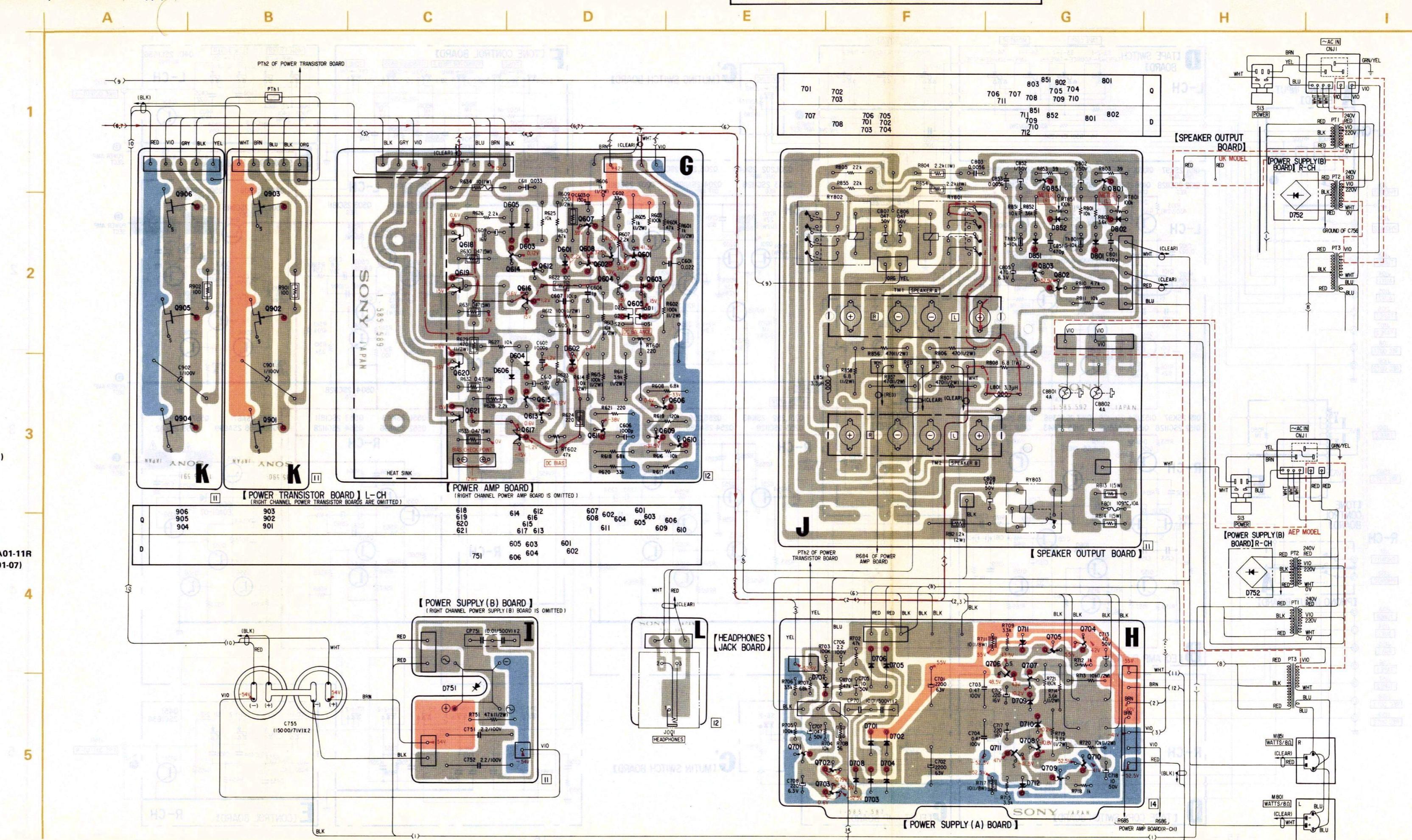
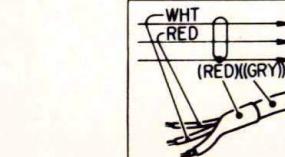


Q705, 707: 2SC634

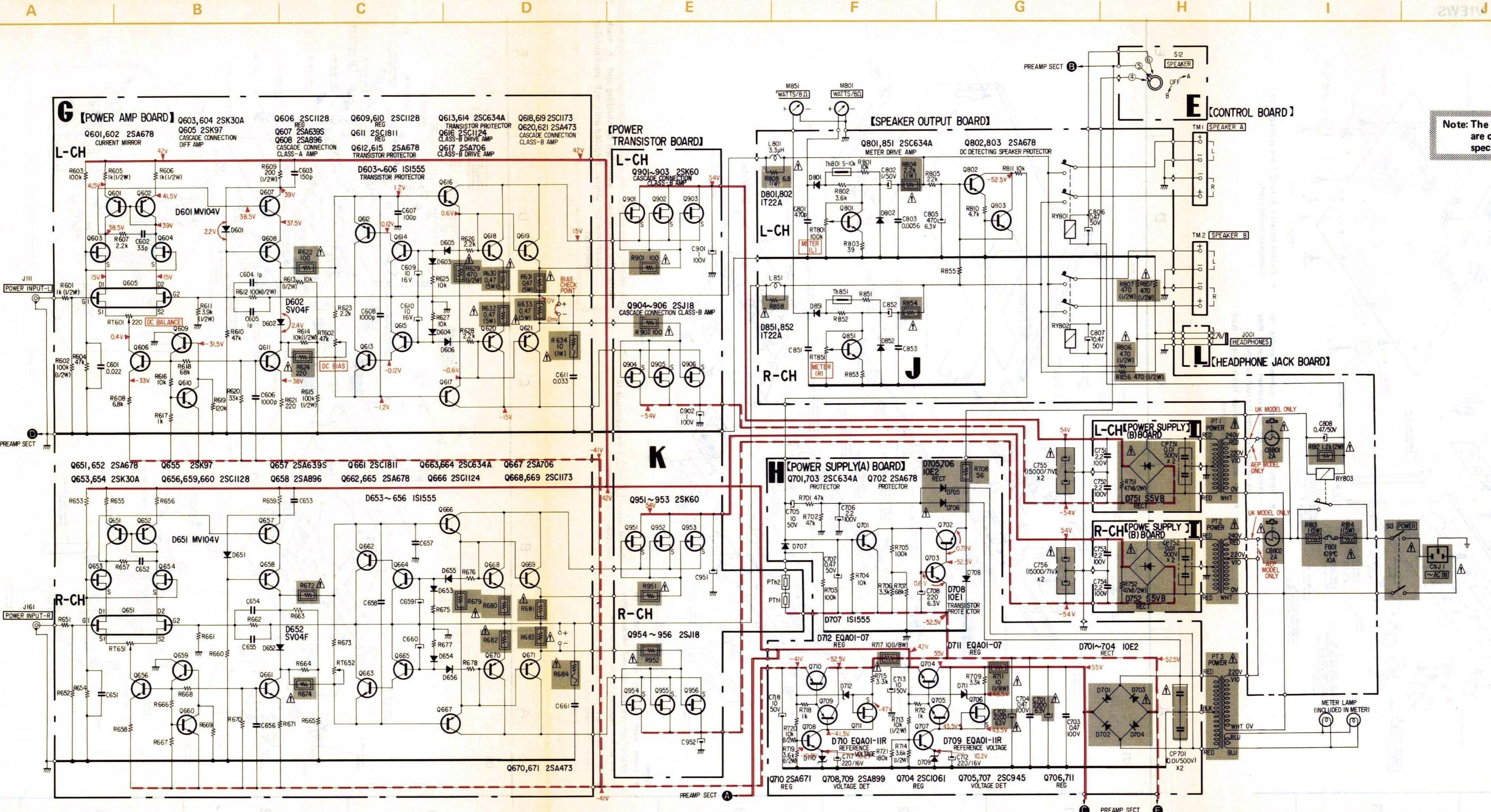


Note:

- Color code of sleeveing over the end of the jacket. •  : B+ pa



4-5. SCHEMATIC DIAGRAM – Power Amplifier and Power Supply Sections –



Note: The components identified by shading and  mark are critical for safety. Replace only with part number specified.

Note: Components for right channel have same values as for left channel. Reference numbers are coded from.
 All capacitors are in μF unless otherwise noted. $\text{pF} = \mu\text{F}$
 50WV or less are not indicated except for electrolytics.
 All resistors are in ohms, $\frac{1}{4}\text{W}$ unless otherwise noted.
 $\text{k}\Omega = 1000\Omega$, $\text{M}\Omega = 1000\text{k}\Omega$

 : nonflammable resistor.

 : fusible resistor.

 : B+ bus.

 : B- bus.

 : panel designation.

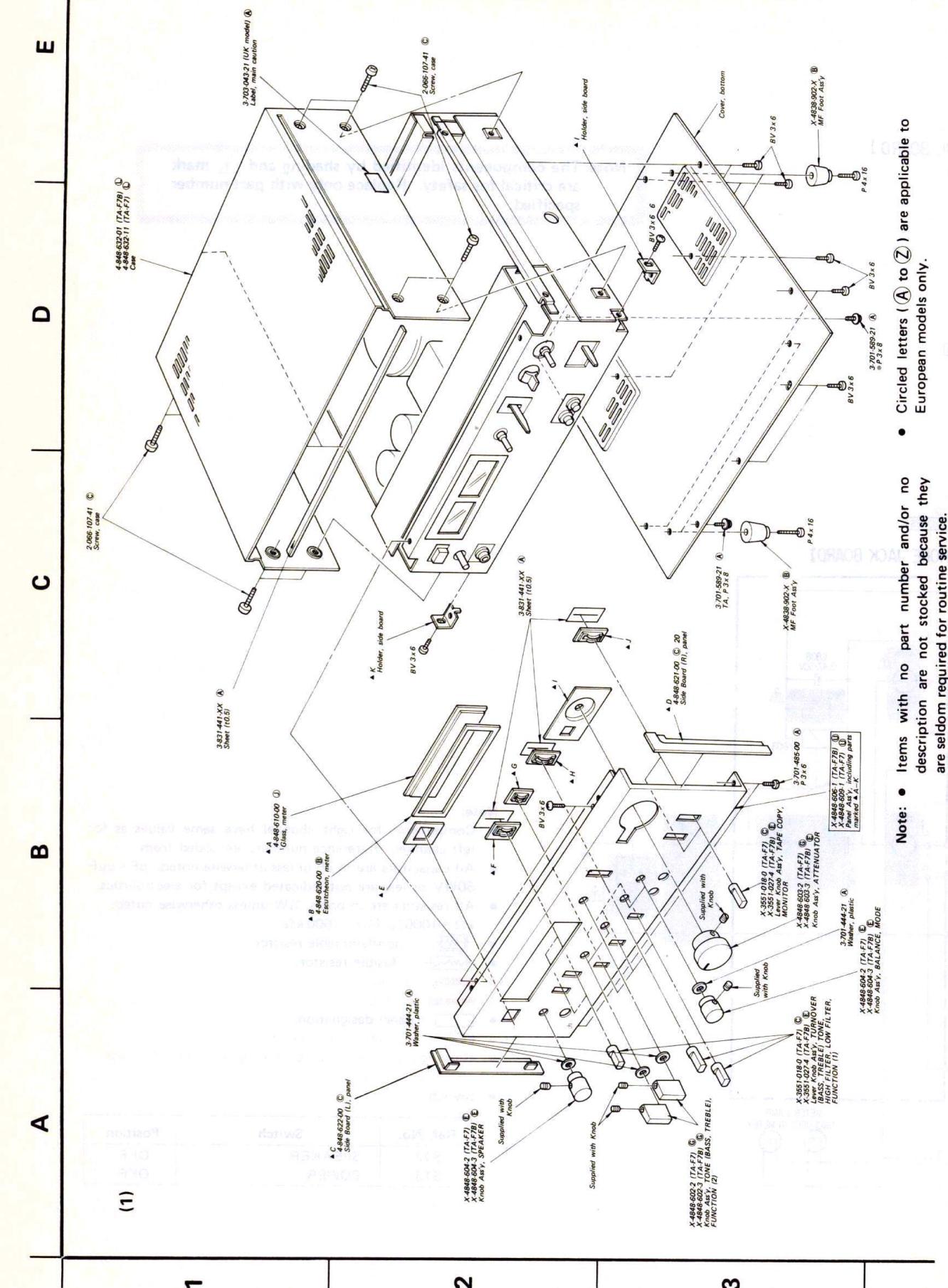
 : adjustment for repair.

Readings are taken under no signal conditions with a VOM ($20\text{k}\Omega/\text{V}$).

Switch

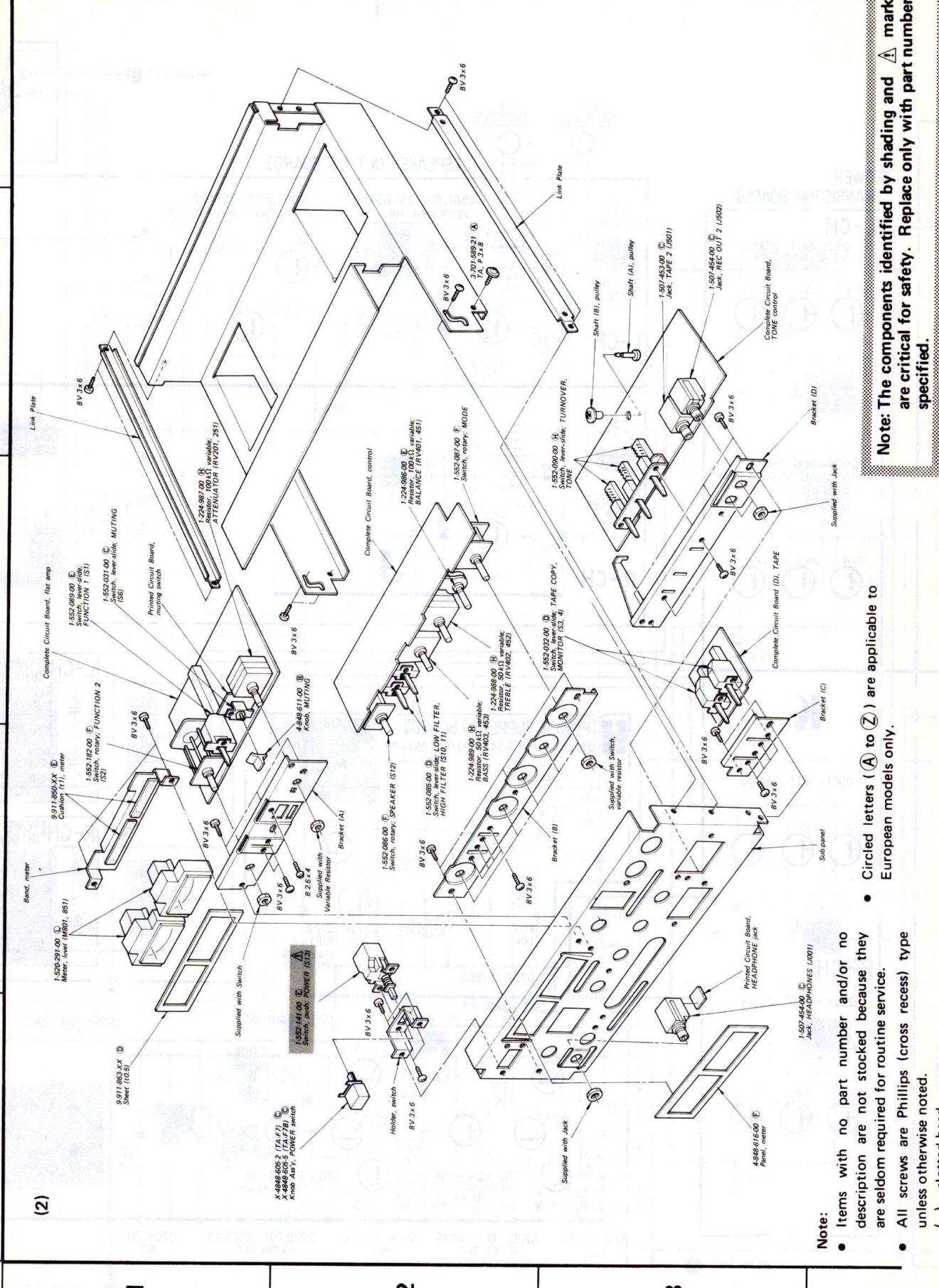
Ref. No.	Switch	Position
S12	SPEAKER	OFF
S13	POWER	OFF

SECTION 5 EXPLODED VIEWS

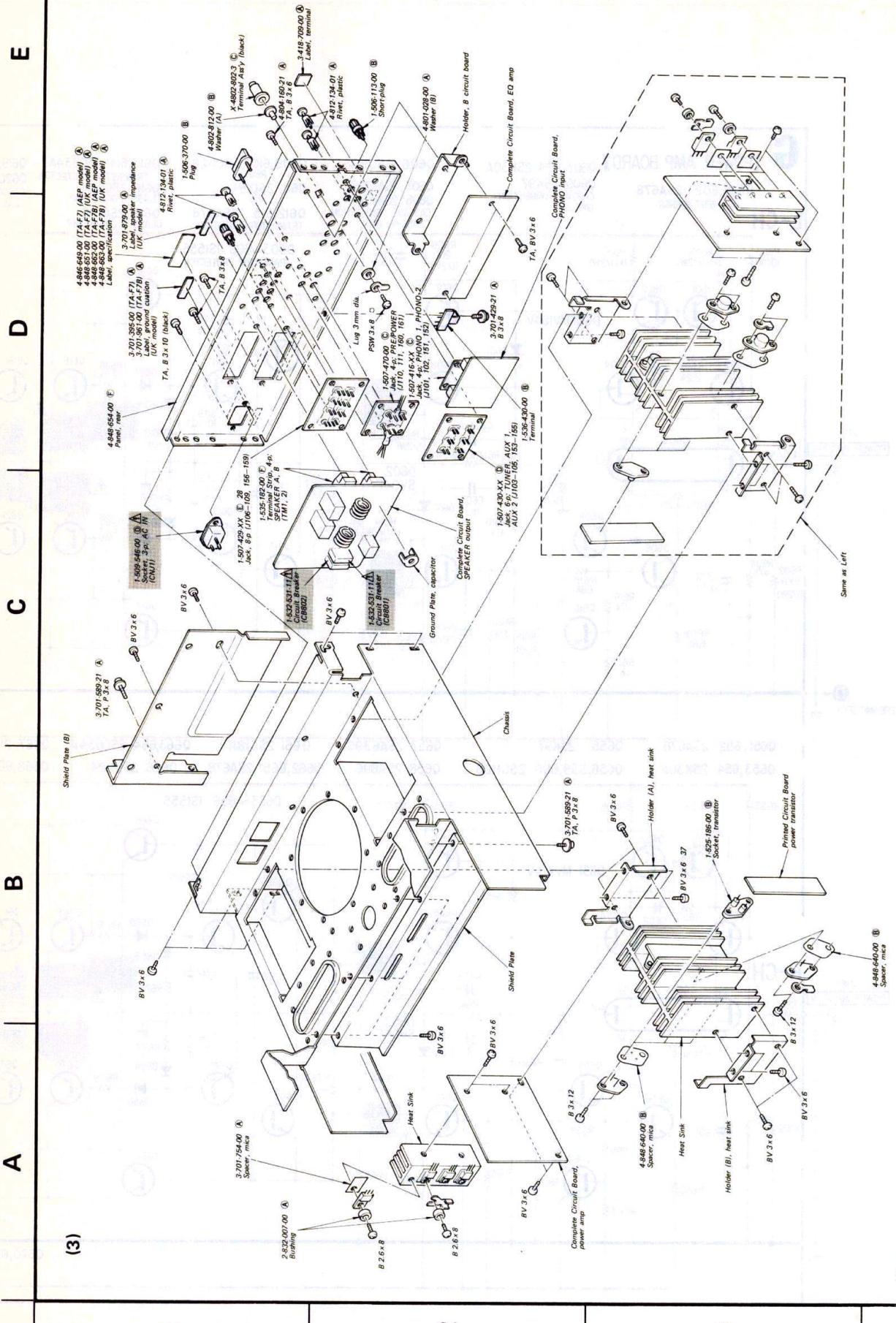


- All screws are Phillips (cross recess) type unless otherwise noted.
(-) = slotted head

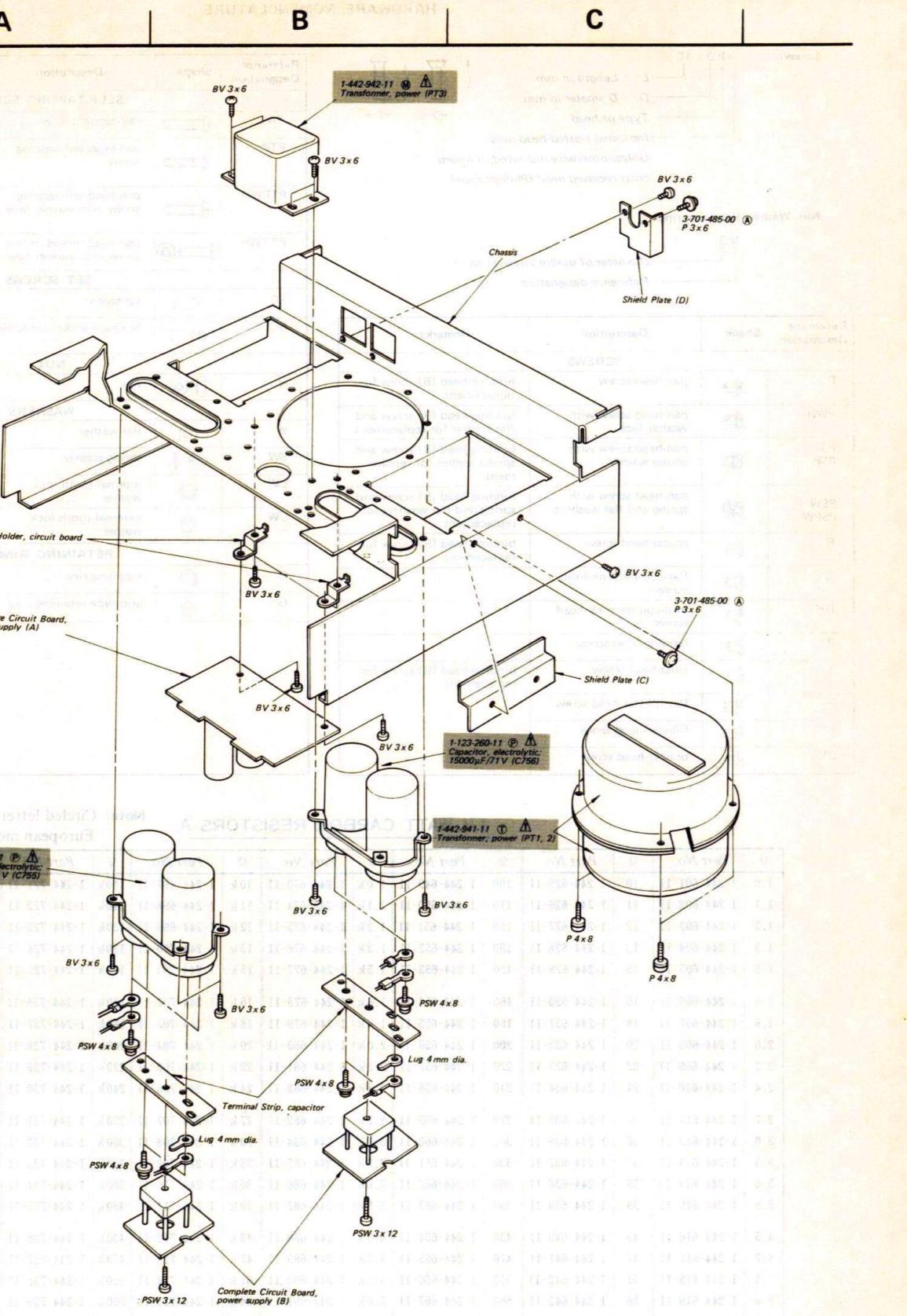
D **C**



(-) = slotted head



Note: The components identified by shading and mark are critical for safety. Replace only with part number.



Note:

- Items with no part number and/or no description are not stocked because they are seldom required for routine service.
- All screws are Phillips (cross recess) type unless otherwise noted.
(-) = slotted head
- Circled letters (Ⓐ to Ⓛ) are applicable to European models only.

Note: The components identified by shading and Ⓛ mark are critical for safety. Replace only with part number specified.

SECTION 6 ELECTRICAL PARTS LIST

- Circled letters (Ⓐ to Ⓛ) are applicable to European models only.

Ref. No.	Part No.	Description	Ref. No.	Part No.	Description	Ref. No.	Part No.	Description	Ref. No.	Part No.	Description
PRINTED CIRCUIT BOARD											
1	1-585-589-12	Ⓐ Power Amp	⇒ Q603,604	Ⓑ 2SK30A-GR		⇒ D501,551	Ⓑ EQB01-07		C102,152	1-101-005-11	Ⓐ 0.022
2	Complete Circuit Board, power supply (A)		⇒ Q653,654	Ⓕ 2SK97		⇒ D601,651	Ⓒ KB462S		C103,153	1-102-973-11	Ⓐ 100p
3	Complete Circuit Board, power supply (B)		Q605,655	Ⓒ 2SC1128		D602,652	Ⓒ SV04S		C104,154	1-130-131-11	Ⓑ 1600p 100V polyethylene
4	PSW 4x8		Q606,656	Ⓒ 2SA639S		D603-606	Ⓑ 1S1555		C105,155	1-130-132-11	Ⓑ 5600p 100V polyethylene
5	PSW 4x8		Q607,657			D653-656			C106,156		
SEMICONDUCTORS											
1			Q608,658	Ⓒ 2SA896		⇒ D701-706 Ⓛ	Ⓑ 10E2		C107,157	1-131-217-11	Ⓑ 2.2 35V tantalum
2			Q609,659	Ⓒ 2SC1128		D707	Ⓒ 1S1555		C108,158	1-102-959-11	Ⓐ 22p
3			Q610,660	Ⓒ 2SK43-2		⇒ D708	Ⓑ 10E2		C109,159	1-130-122-11	Ⓑ 1000p 100V polyethylene
4			Q101,151	Ⓕ 2SK97		⇒ D709,710	Ⓑ EQB01-11Z		C110,160	1-123-250-11	Ⓑ 2.2 100V elect
5			Q102-104	Ⓒ 2SC1128		⇒ D711,712	Ⓑ EQB01-07		C111,161		
TRANSISTORS											
1			Q152-154	⇒ Q105,155	Ⓒ 2SA678	D751,752 Ⓛ	Ⓕ S5VB20		C112,162	1-130-133-11	Ⓑ 56000p 100V polyethylene
2			Q105,155	Ⓒ 2SK43-2					C201,251	1-102-971-11	Ⓐ 82p
3			Q106,107	Ⓒ 2SA639S		D801,851	Ⓑ 1T22M		C202,252	1-102-824-11	Ⓐ 470p
4			Q156,157	Ⓒ 2SA896		D802,852		C203,253	1-131-295-11	Ⓒ 100 6.3V tantalum	
5			Q108,158	Ⓒ 2SA896				C204,254	1-130-133-11	Ⓑ 56000p 100V polyethylene	
THERMISTORS											
1			Q109,159	Ⓒ 2SC1811		Th801,851	1-800-202-XX	Ⓐ Thermistor, S-10K	C205,255	1-108-227-12	Ⓐ 0.001
2			Q201,202	Ⓕ 2SK43-3A		PTh1,2	1-800-427-00	Ⓑ Thermistor	C208		
3			Q251,252	Ⓒ 2SC1128					C401,451	1-108-360-12	Ⓐ 0.039 mylar
4			Q203,253	Ⓒ 2SA473				C402,452	1-108-364-12	Ⓑ 0.18 mylar	
5			Q204,254	Ⓒ 2SA896				C403,453	1-108-581-12	Ⓑ 0.012 mylar	
COILS											
1			Q205,206	Ⓒ 2SC1128		L401,451	1-407-879-00	Ⓑ 33 mH, microinductor	C404,454	1-108-254-12	Ⓑ 0.22 mylar
2			Q255,256	Ⓒ 2SC1811		L801,851	1-420-879-00	Ⓑ Coil	C405,455		
3			Q207,257	Ⓒ 2SC634A				C501,551	1-102-115-11	Ⓐ 560p	
4			Q401,451	Ⓑ 2SC1636				C502,552	1-108-228-12	Ⓐ 0.0015 mylar	
5			⇒ Q501,551	Ⓕ 2SK43-3A				C503,553			
TRANSFORMERS											
1			Q502,552	Ⓒ 2SA896		PT1,2 Ⓛ	1-442-941-11	Ⓣ Power	C504,554	1-108-237-12	Ⓐ 0.0068 mylar
2			Q503,553	Ⓒ 2SC1811		PT3 Ⓛ	1-442-942-11	Ⓜ Power	C505,555		
3			Q504,554	Ⓒ 2SC1128				C506,556	1-108-360-12	Ⓐ 0.039 mylar	
4			Q505	Ⓓ 2SC1061				C507,557	1-108-364-12	Ⓑ 0.18	
5			Q555	Ⓔ 2SA671				C508,558	1-102-125-11	Ⓐ 4700p	
CAPACITORS											
1			⇒ Q506	Ⓑ 2SC634A				C509,559	1-131-239-11	Ⓑ 6.8 35V tantalum	
2			Q556	Ⓒ 2SA899				C510,560			
3			Q507	Ⓒ 2SA899				C511,561	1-130-083-11	Ⓒ 1 100V polyethylene	
4			⇒ Q557	Ⓑ 2SC634A				C514,564	1-121-411-11	Ⓑ 47 50V elect	
5			Q508	Ⓒ 2SC634A				C517,567	1-130-086-11	Ⓑ 0.47 100V polyethylene	
DIODES											
1			Q558	Ⓒ 2SA899				C601,651	1-101-005-11	Ⓐ 0.022	
2			⇒ Q509,559	Ⓒ 2SK42-2				C602,652	1-102-963-11	Ⓐ 33p	
3			Q590,559	Ⓒ 2SC634A				C603,653	1-101-361-11	Ⓐ 150p	
4			Q559	Ⓒ 2SA899				C604,654	1-102-934-11	Ⓐ 1p	
5			Q560	Ⓒ 2SK42-2				C605,655			
Diodes											
1			Q601,602	Ⓒ 2SA678							
2			Q651,652	Ⓒ 2SA678							
3			D101,151	Ⓑ 1S1555							
4											
5											

- ⇒ Due to standardization, interchangeable replacements may be substituted for parts specified in the diagrams.

All capacitors are in μF and ceramic unless otherwise noted.
50WV or less are not indicated except for electrolytics. pF = μF , elect = electrolytic

⇒ Due to standardization, interchangeable replacements may be substituted for parts specified in the diagrams.

- Circled letters (Ⓐ to Ⓛ) are applicable to European models only.

Note: The components identified by shading and Ⓛ mark are critical for safety. Replace only with part number specified.

Note: Circled letters (A) to (Z) are applicable to European models only.

Ref. No.	Part No.	Description
C606,656	1-101-001-11	(A) 1000p
C607,657	1-102-973-11	(A) 100p
C608,658	1-101-001-11	(A) 1000p
C609,659	1-121-651-11	(A) 10 16V elect
C610,660	1-108-244-12	(A) 0.033 mylar
C701,702 (A) 1-123-261-11	(E) 2200 63V elect	
C703,704	1-130-086-11	(B) 0.47 100V polyethylene
C705	1-123-183-11	(A) 10 50V elect
C706	1-123-250-11	(B) 2.2 100V elect
C707	1-121-726-11	(A) 0.47 50V elect
C708	1-121-419-11	(B) 220 6.3V elect
C712,717	1-121-421-11	(B) 220 16V elect
C713,718	1-121-738-11	(B) 10 50V elect
C751-754	1-130-084-11	(D) 2.2 100V polyethylene
C755,756 (A) 1-123-260-11	(P) 15000 71V elect	
C801,851	1-102-824-11	(A) 470p
C802,852	1-121-391-11	(A) 1 50V elect
C803,853	1-108-355-12	(A) 0.0056 mylar
C805	1-121-424-11	(B) 470 6.3V elect
C806-808	1-121-726-11	(A) 0.47 50V elect
C901,951	1-119-372-11	1 100V elect
C902,952		

RESISTORS

All resistors are in ohms. Common 1/4W carbon resistors are omitted.
Check schematic diagram for values.

R101,151	1-244-914-11	(A) 51k 1/4W
R102,152	1-244-873-11	(A) 1k 1/4W
R103,153	1-244-864-11	(A) 430 1/4W
R104,154	1-244-909-11	(A) 33k 1/4W
R105,155	1-244-865-11	(A) 470 1/4W
R107,157	1-244-873-11	(A) 1k 1/4W
R108,158	1-214-172-11	(B) 47k 1/4W metal oxide
R109,159	1-214-473-11	(B) 576k 1/4W metal oxide
R116,166	1-244-945-11	(A) 1M 1/4W
R117,167	1-244-909-11	(A) 33k 1/4W
R118,168	1-244-873-11	(A) 1k 1/4W

Note: The components identified by shading and (A) mark are critical for safety. Replace only with part number specified.

Note: Circled letters (A) to (Z) are applicable to European models only.

Ref. No.	Part No.	Description
R120,170	1-244-873-11	(A) 1k 1/4W
R202,252	1-244-919-11	(A) 2k 1/4W
R203,253	1-244-945-11	(A) 1M 1/4W
R204,254	1-244-873-11	(A) 1k 1/4W
R205,255	1-244-905-11	(A) 22k 1/4W
R206,256	1-244-873-11	(A) 10 1/8W
R208,258	1-244-877-11	(A) 1.5k 1/4W
R209,259	1-244-897-11	(A) 10k 1/4W
R214,264	1-244-873-11	(A) 1k 1/4W
R219	1-244-881-11	(A) 2.2k 1/4W
R301,351	1-244-897-11	(A) 10k 1/4W
R302,352	1-244-897-11	(A) 10k 1/4W
R509,559	1-244-873-11	(A) 1k 1/4W
R510,560	1-244-945-11	(A) 1M 1/4W
R511,561	1-244-893-11	(A) 6.8k 1/4W
R512,562	1-244-881-11	(A) 2.2k 1/4W
R513,563	1-244-897-11	(A) 10k 1/4W
R514,564	1-244-861-11	(A) 330 1/4W
R520,570	1-244-897-11	(A) 10k 1/4W
R521,571	1-244-856-11	(A) 200 1/4W
R524,574	(A) 1-212-869-11	(A) 33 1/4W fusible
R527,577	(A) 1-212-990-11	(A) 220 1/4W fusible

Note: Circled letters (A) to (Z) are applicable to European models only.

Ref. No.	Part No.	Description
R711,717	(A) 1-211-409-11	(A) 10 1/8W
R713,720	1-244-897-11	(A) 10k 1/4W
R714,719	1-244-886-11	(A) 3.6k 1/4W
R751,752	(A) 1-244-913-11	(A) 47k 1/4W
R804,854	(A) 1-213-147-11	(A) 2.2k 1W metal oxide
R806,856	(A) 1-244-865-11	(A) 470 1/4W
R808,858	(A) 1-212-370-11	(A) 6.8 1W
R812	(A) 1-206-666-11	(A) 1.2k 2W metal oxide
R813,814	(A) 1-217-160-11	(A) 1 5W metal oxide
R901,951	(A) 1-211-522-11	(A) 100 1/4W
R902,952	(A) 1-211-522-11	(A) 100 1/4W
RT601,651	1-224-487-00	(B) 220 adjustable
RT602,652	1-224-661-00	(B) 47k adjustable
RT801,851	1-224-492-00	(B) 100k adjustable
RV201,251	2-224-987-00	(H) 100k, variable; ATTENUATOR
RV401,451	1-224-986-00	(E) 100k, variable; BALANCE
RV402,452	1-224-988-00	(H) 50k, variable; TREBLE
RV403,453	1-224-989-00	(H) 51k, variable; BASS

Note: Circled letters (A) to (Z) are applicable to European models only.

Ref. No.	Part No.	Description
J106-109	1-507-429-XX	(E) 8p, TAPE 1, TAPE 2
J156-159		REC OUT 1, REC OUT 2
J110,160	1-507-470-00	(C) 4p, PRE/POWER
J111,161		
J501	1-507-453-00	(C) TAPE 2
J502	1-507-454-00	(C) REC OUT 2
CNJ	(A) 1-509-546-00	(D) 3p, socket; AC IN

MISCELLANEOUS

CB801,802	(A) 1-532-531-11	(C) Circuit Breaker, 2A
CP701	(A) 1-102-355-11	(B) Encapsulated Component
CP751,752	(A) 1-212-355-11	(B) Encapsulated Component

F801

F801	(A) 1-532-496-11	(C) Fuse 10A
M801,851	1-520-291-00	(L) Meter, level
RY001,002	1-515-277-00	(F) Relay
RY801,802	1-515-257-00	(H) Relay (TA-F7)
RY803	1-515-293-00	(H) Relay (TA-F7B)
RY803	1-515-278-00	(F) Relay
TM1,2	1-535-182-00	(F) Terminal Strip, 4p; SPEAKER A, B

SWITCHES

S1	1-552-089-00	(E) Lever Slide, FUNCTION (1)
S2	1-552-182-00	(F) Rotary Slide, FUNCTION (2)
S3,4	1-552-032-00	(D) Lever Slide, TAPE COPY, MONITOR
S5	1-552-087-00	(F) Rotary, MODE
S6	1-552-031-00	(C) Lever Slide, MUTING
S7-9	1-552-090-00	(H) Lever Slide, TURNOVER (BASS, TREBLE)/TONE
S10,11	1-552-085-00	(D) Lever Slide, LOW FILTER, HIGH FILTER
S12	1-552-086-00	(F) Rotary, SPEAKER
S13	(A) 1-552-141-00	(E) Pushbutton, POWER

JACKS

J001	1-507-454-00	(C) HEADPHONES
J101,151	1-507-416-XX	(C) 4p, PHONO 1, PHONO 2
J102,152	1-507-416-XX	(C) 4p, PHONO 1, PHONO 2
J103-105	1-50	